



#### Vishay Semiconductors

# Small Signal Switching Diode

#### **Features**

- Silicon Epitaxial Planar Diodes
- Fast switching diode in case SOT-23, especially suited for automatic insertion.
- This diodes are also available in other case styles including: the DO-35 case with the type designation 1N4148, the Mini-MELF case with the type designation LL4148, and the SOD-123 case with the type designation 1N4148W-V.
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

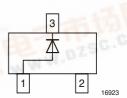
#### **Mechanical Data**

Case: SOT-23 Plastic case Weight: approx. 8.8 mg Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS08 / 3 k per 7" reel (8 mm tape), 15 k/box







#### **Parts Table**

Part	Ordering code	Marking	Remarks
IMBD4148-V	IMBD4148-V-GS18 or IMBD4148-V-GS08	A2	Tape and Reel

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage	- C COM	V <sub>R</sub>	75	V
Peak reverse voltage	WW.DZ3	V <sub>RM</sub>	100	V
Rectified current (average) half wave rectification with resist.	$T_{amb} = 25 \text{ °C}, \ge f \ge 50 \text{ Hz}$	I <sub>F(AV)</sub>	150 <sup>1)</sup>	mA
Surge forward current	t < 1 s, T <sub>j</sub> = 25 °C	I <sub>FSM</sub>	500	mA
Power dissipation	up to T <sub>amb</sub> = 25 °C	P <sub>tot</sub>	350 <sup>1)</sup>	mW

<sup>1)</sup> Device on fiberglass substrate, see layout (SOT-23).

#### **Thermal Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	NW.DZS	R <sub>thJA</sub>	450 <sup>1)</sup>	°C/W
Junction temperature		T <sub>j</sub>	150	°C
Storage temperature range		T <sub>S</sub>	- 65 to + 150	°C

<sup>1)</sup> Device on fiberglass substrate, see layout (SOT-23).

## **IMBD4148-V**

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#### **Electrical Characteristics**

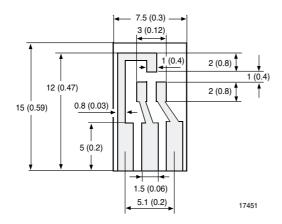
 $T_{amb}$  = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I <sub>F</sub> = 10 mA	V <sub>F</sub>			1.0	V
Leakage current	V <sub>R</sub> = 70 V	I <sub>R</sub>			2.5	μΑ
	V <sub>R</sub> = 70 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			50	μΑ
	V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			30	μΑ
Diode capacitance	$V_F = V_R = 0$	C <sub>tot</sub>			4	pF
Reverse recovery time (see figures)	$I_F = 10 \text{ mA}, I_R = 10 \text{ mA},$ $V_R = 6 \text{ V}, R_L = 100 \Omega$	t <sub>rr</sub>			4	ns

## Layout for R<sub>thJA</sub> test

Thickness:

Fiberglass 1.5 mm (0.059 in.) Copper leads 0.3 mm (0.012 in.)



### Typical Characteristics (Tamb = 25 °C unless otherwise specified)

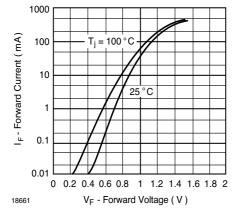


Figure 1. Forward Current vs. Forward Voltage

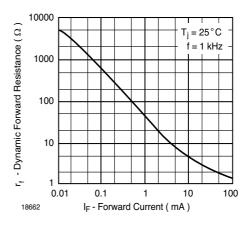


Figure 2. Dynamic Forward Resistance vs. Forward Current



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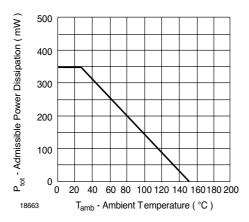


Figure 3. Admissible Power Dissipation vs. Ambient Temperature

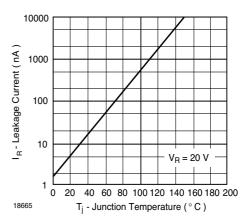


Figure 5. Leakage Current vs. Junction Temperature

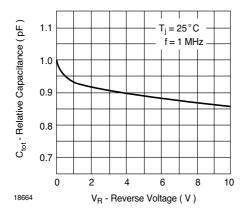


Figure 4. Relative Capacitance vs. Reverse Voltage

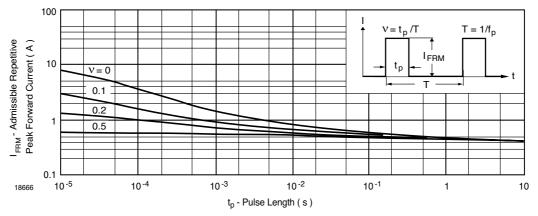


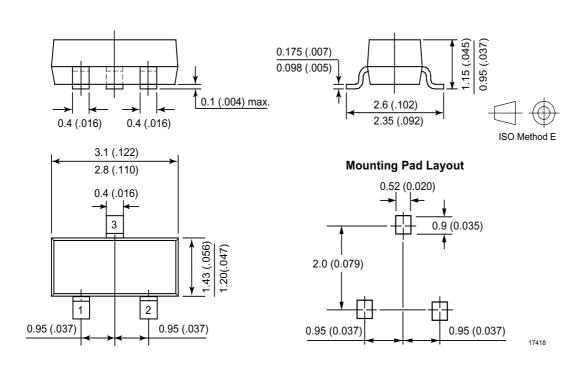
Figure 6. Admissible Repetitive Peak Forward Current vs. Pulse Duration

# **IMBD4148-V**

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## **Package Dimensions in mm (Inches)**



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#### **Vishay Semiconductors**

#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

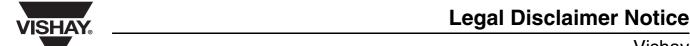
Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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